High Performance 200-1000 KHz Oscillator



■ Features, Benefits and Applications

- 200 1000 kHz frequency range (contact SiTime for <200 kHz)
- Frequency stability as low as ± 20 PPM
- LVCMOS/LVTTL compatible output
- Typical current consumption of 5.7 mA in active mode
- Standby or output enable modes
- Four industry-standard packages: 2.5 x 2.0, 3.2 x 2.5, 5.0 x 3.2, 7.0 x 5.0 mm
- All-silicon device with outstanding reliability of 2 FIT, 10x improvement over quartz-based devices, enhancing system MTBF
- Outstanding mechanical robustness for portable applications
- Ultra short lead time
- Ideal for consumer electronics, audio applications

■ Specifications

Electrical Characteristics

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Output Frequency Range	f	200	-	1000	kHz	Contact SiTime for <200 kHz	
Frequency Stability	F_stab	-20	-	+20	PPM	Inclusive of: Initial stability, operating temperature, rated power,	
		-25	-	+25	PPM	supply voltage change, load change, shock and vibration.	
		-30	-	+30	PPM	± 20 PPM available in extended commercial	
		-50	-	+50	PPM	temperature only	
Aging	Ag	-1.0	-	1.0	PPM	1st year at 25°C	
Operating Temperature Range	T_use	-20	-	+70	°C	Extended commercial	
	_	-40	_	+85	°C	Industrial	
Supply Voltage	Vdd	1.71	1.8	1.89	V		
, .		2.25	2.5	2.75	V	_	
		2.52	2.8	3.08	V		
		2.97	3.3	3.63	V		
Current Consumption	ldd	_	5.9	6.9	mA	No load condition, f = 400 KHz, Vdd = 2.5 V, 2.8 V or 3.3 V	
·		_	5.7	6.6	mA	No load condition, f = 400 KHz, Vdd = 1.8 V	
Standby Current	I std	_	2.4	4.3	μА	ST = GND, Vdd = 3.3 V, Output is weakly pulled down	
	_	-	1.2	2.2	μА	ST = GND, Vdd = 2.5 or 2.8 V, Output is weakly pulled down	
		-	0.4	0.8	μA	ST = GND, Vdd = 1.8 V, Output is weakly pulled down	
Duty Cycle	DC	45	50	55	%	All Vdds	
Rise/Fall Time	Tr, Tf	_	1.0	2.0	ns	20% - 80% Vdd=2.5V or 2.8V, 3.3V, 15pF load	
		_	1.3	2.5	ns	20% - 80% Vdd=1.8V, 15pF load	
Output Voltage High	VOH	90%	-	-	Vdd	IOH = -4 mA (Vdd = 3.3 V) IOH = -3 mA (Vdd = 2.8 V and Vdd = 2.5 V) IOH = -2 mA (Vdd = 1.8 V)	
Output Voltage Low	VOL	-	-	10%	Vdd	IOL = 4 mA (Vdd = 3.3 V) IOL = 3 mA (Vdd = 2.8 V and Vdd = 2.5 V) IOL = 2 mA (Vdd = 1.8 V)	
Output Load	Ld	ı	-	15	pF	At maximum frequency and supply voltage. Contact SiTime for higher output load option	
Input Voltage High	VIH	70%	-	_	Vdd	Pin 1, OE or ST	
Input Voltage Low	VIL	_	_	30%	Vdd	Pin 1, OE or ST	
Startup Time	T_osc	_	-	10	ms	Measured from the time Vdd reaches its rated minimum value	
Resume Time	T_resume	_	3	4	ms	Measured from the time ST pin crosses 50% threshold	
RMS Period Jitter	T_jitt	-	11	17	ps	f = 400 KHz, Vdd = 2.5 V, 2.8 V or 3.3 V	
		_	12	17	ps	f = 400 KHz, Vdd = 1.8 V	

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■ Specifications (Cont.)

Pin Description Tables

Pin #1 Functionality				
OE				
H or Open ^[1] : specified frequency output				
L: output is high impedance				
ST				
H or Open: specified frequency output				
L: output is low level (weak pull down). Oscillation stops				

Pin Map				
Pin	Connection			
1	OE/ST			
2	GND			
3	CLK			
4	VDD			

Absolute Maximum Table

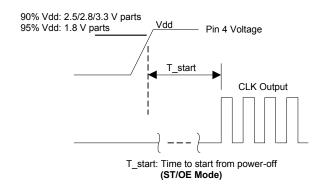
Attempted operation outside the absolute maximum ratings of the part may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

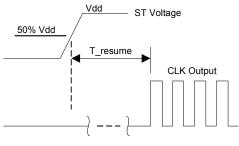
Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	°C
Vdd	-0.5	4	V
Electrostatic Discharge	-	6000	V
Theta JA (with copper plane on Vdd and GND)	-	75	°C/W
Theta JC (with PCB traces of 0.010 inch to all pins)	-	24	°C/W
Soldering Temperature (follow standard Pb free soldering guidelines)	-	260	°C
Number of Program Writes	-	1	NA
Program Retention over -40 to 125°C, Process, Vdd (0 to 3.65 V)	1,000+	-	years

Environmental Compliance

Parameter	Condition/Test Method		
Mechanical Shock	MIL-STD-883F, Method 2002		
Mechanical Vibration	MIL-STD-883F, Method 2007		
Temperature Cycle	JESD22, Method A104		
Solderability	MIL-STD-883F, Method 2003		
Moisture Sensitivity Level	MSL1 @ 260°C		

Startup and Resume Timing Diagram





T_resume: Time to resume from ST (ST Mode Only)

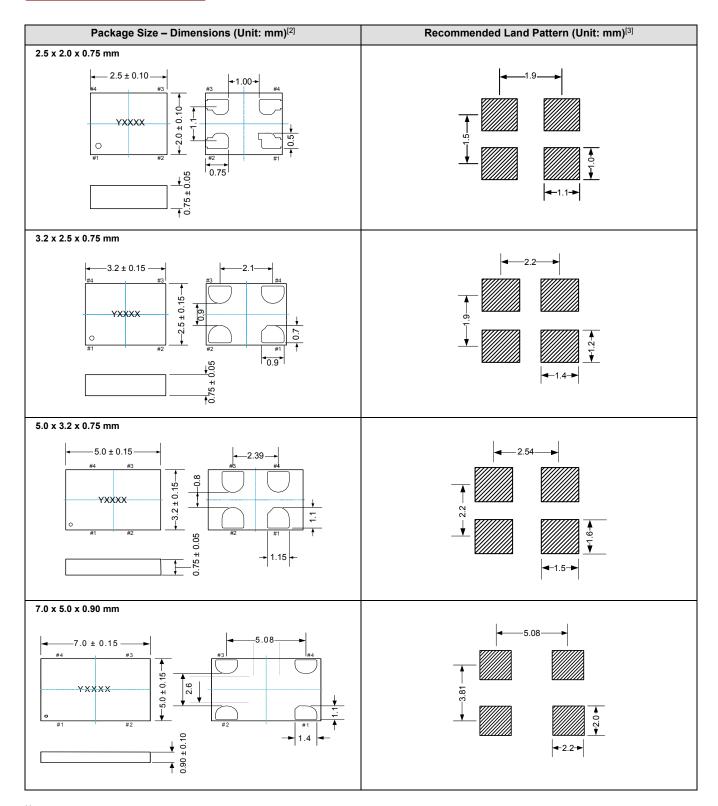
Note:

1. In 1.8 V mode, a resistor of <100 k Ω between OE pin and VDD is recommended.

High Performance 200-1000 KHz Oscillator



■ Dimensions and Land Patterns



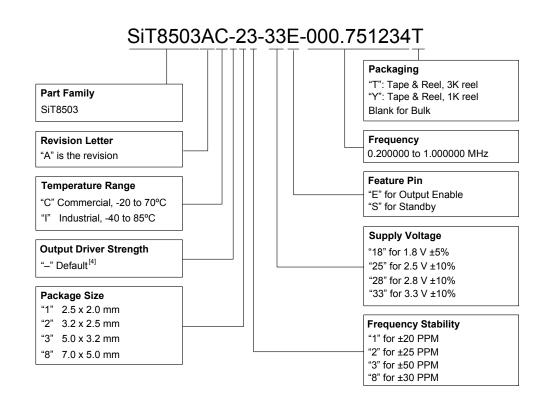
- Notes:
 2. Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
 3. A capacitor of value 0.1 μF between Vdd and GND is recommended.

High Performance 200-1000 KHz Oscillator Advanced Information



■ Part No. Guide - How to Order

The Part No. Guide is for reference only. For real-time customization and exact part number, use the SiTime Part Number Generator.



Notes:

4. Contact SiTime for different drive strength options for driving higher loads or reducing EMI.

Frequency Stability vs. Temperature Range Options

Frequency	Temperature	Supply Voltage			
Stability (PPM)	Range	1.8 V	2.5 V	2.8 V	3.3 V
±20	C (-20 to +70°C)	✓	✓	✓	✓
	I (-40 to +85°C)	-	-	-	-
±25	C (-20 to +70°C) I (-40 to +85°C)	✓	✓	✓	✓
±30	C (-20 to +70°C) I (-40 to +85°C)	√	✓	✓	✓
±50	C (-20 to +70°C) I (-40 to +85°C)	✓	✓	✓	✓

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